USHIO Applying Light to Life

Product Status Information

HL83013MG is Not Recommended for New Design (NRND) status. Please refer to successor product below for new design and adoption.

NRND Product	Successor Product		
HL83013MG	HL85023MG		
https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL83013MG.pdf	https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL85023MG.pdf		

For the "Product Life Cycle" definition, please refer to below link. Japanese; https://www.ushio.co.jp/jp/laser/news/500958.html

English; https://www.ushio.co.jp/en/laser/news/500958.html

HL83013MG

830nm/50mW GaAlAs Laser Diode

Outline

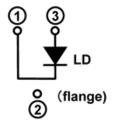
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(Unit:mm)

Internal Circuit

HL83013MG



Features

- Operation temperature: -10~+60°C
- Optical output power: 50mW(CW)
- Infrared lasing: 830nm Typ.
- Low operating voltage: 2.4V Max.
- Package: φ5.6mm
- Single transverse mode
- TE mode oscillation

Application

- Sensor application
- Night vision
- Machine vision
- Light source of optical equipments



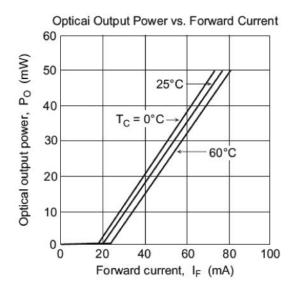
Absolute Maximum Ratings (Tc=25°C)

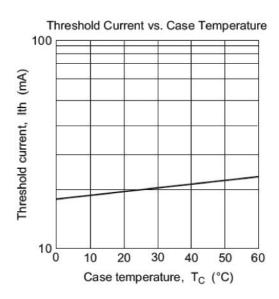
Item	Symbol	Ratings	Unit
Optical output power	Ро	50	mW
LD Reverse Voltage	V _{R(LD)}	2	V
Operating Temperature	Topr	-10 ~ +60	°C
Storage Temperature	Tstg	-40 ~ +85	°C

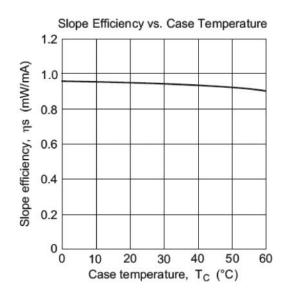
Optical and Electrical Characteristics (Tc=25°C)

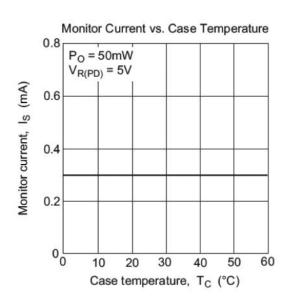
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition			
Threshold current	Ith	-	20	40	mA	-			
Operating current	lop	-	75	100	mA	Po=50mW			
Operating voltage	Vop	-	1.9	2.4	V	Po=50mW			
Beam divergence Parallel to the junction	θ//	6	9	12	0	Po=50mW, FWHM			
Beam divergence Perpendicular to the junction	θ⊥	18	22	26	o	Po=50mW, FWHM			
Lasing Wavelength	λр	820	830	840	nm	Po=50mW			

Typical Characteristic Curves









Data Sheet

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Data Sheet

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